

## J500, J501, J502 Current Regulator Diode

### Features

- InterFET [N0016H Geometry](#)
- Low Noise: 5 nV/VHz Typical
- Low Capacitance: 2pF Typical
- RoHS Compliant
- SMT, TH, and Bare Die Package options.

### Applications

- Current Regulation
- Current Limiting

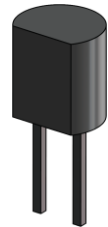
### Description

The 50V InterFET J500, J501, and J502 JFET's are targeted for current regulation and limiting applications. The SOT23 package is pinned out as a standard JFET and is required by the user to connect the Gate to the Source or Drain.

SOT23 Top View



TO-92 Bottom View



### Product Summary

Parameters		J500 Min	J501 Min	J502 Min	Unit
V <sub>OP</sub>	Peak Operating Voltage	50 (typ)	50 (typ)	50 (typ)	V
I <sub>F1</sub>	Forward Current	0.192	0.264	0.344	mA
V <sub>L</sub>	Limiting Voltage	0.8 (typ)	0.9 (typ)	1.1 (typ)	V

### Ordering Information Custom Part and Binning Options Available

Part Number	Description	Case	Packaging
J500; J501; J502	Through-Hole	TO-92-2L	Bulk
SMPJ500; SMPJ501; SMPJ502	Surface Mount	SOT23	Bulk
SMPJ500TR; SMPJ501TR; SMPJ502TR	7" Tape and Reel: Max 3,000 Pieces 13" Tape and Reel: Max 9,000 Pieces	SOT23	Minimum 1,000 Pieces Tape and Reel
J500COT; J501COT; J502COT	Chip Orientated Tray (COT Waffle Pack)	COT	400/Waffle Pack
J500CFT; J501CFT; J502CFT	Chip Face-up Tray (CFT Waffle Pack)	CFT	400/Waffle Pack



**Disclaimer:** It is the Buyers responsibility for designing, validating and testing the end application under all field use cases and extreme use conditions. Guaranteeing the application meets required standards, regulatory compliance, and all safety and security requirements is the responsibility of the Buyer. These resources are subject to change without notice.

## Electrical Characteristics

### Maximum Ratings (@ T<sub>A</sub> = 25°C, Unless otherwise specified)

Parameters	Value	Unit
V <sub>OP</sub> Peak Operating Voltage	50	V
I <sub>FG</sub> Continuous Forward Gate Current	20	mA
P <sub>D</sub> Continuous Device Power Dissipation	360	mW
P Power Derating	3.27	mW/°C
T <sub>J</sub> Operating Junction Temperature	-55 to 125	°C
T <sub>STG</sub> Storage Temperature	-65 to 150	°C

### Static Characteristics (@ T<sub>A</sub> = 25°C, Unless otherwise specified)

Parameters	Conditions	J500			J501			J502			Unit
		Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	
I <sub>F1</sub> Forward Current	V <sub>F</sub> = 25V	0.192	0.240	0.288	0.264	0.33	0.396	0.344	0.43	0.516	mA
V <sub>L</sub> Limiting Voltage	I <sub>F</sub> = 0.9 I <sub>F(MIN)</sub>		0.8 (typ)	1.2 (typ)		0.9 (typ)	1.3 (typ)		1.1 (typ)	1.5 (typ)	V
V <sub>OP</sub> Peak Operating Voltage	I <sub>F</sub> = 1.1 I <sub>F(MAX)</sub>	50			50			50			V

### Dynamic Characteristics (@ T<sub>A</sub> = 25°C, Unless otherwise specified)

Parameters	Conditions	J500			J501			J502			Unit
		Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	
Z <sub>fi</sub> Dynamic Impedance	V <sub>F</sub> = 25V, f = 1kHz	4	8		2.2	6		1.5	4.4		MΩ
C <sub>F</sub> Anode-Cathode Capacitance	V <sub>F</sub> = 25V, f = 1kHz		2			2			2		pF

## SOT23 (TO-236AB) Mechanical and Layout Data

### Package Outline Data



1. All linear dimensions are in millimeters.
2. Package weight approximately 0.12 grams
3. Molded plastic case UL 94V-0 rated
4. For Tape and Reel specifications refer to InterFET CTC-021 Tape and Reel Specification, Document number: IF39002
5. Bulk product is shipped in standard ESD shipping material
6. Refer to JEDEC standards for additional information.

### Suggested Pad Layout



1. All linear dimensions are in millimeters.
2. The suggested land pattern dimensions have been provided for reference only. A more robust pattern may be desired for wave soldering.